

HI-8585, HI-8586

ARINC 429 Line Driver

February 2017

DESCRIPTION

The HI-8585 and HI-8586 are CMOS integrated circuits designed to directly drive the ARINC 429 bus in an 8-pin package. Two logic inputs control a differential voltage between the output pins producing a +10 volt One, a -10 volt Zero, and a 0 volt Null.

The CMOS/TTL control inputs are translated to ARINC specified amplitudes using on board band-gap reference. A logic input is provided to control the slope of the differential output signal. Timing is set by on-chip resistor and capacitor and tested to be within ARINC requirements.

The HI-8585 has 37.5 ohms in series with each line driver output. The HI-8586 provides the option to bypass part of the output resistance so that series resistance can be used in external protection circuitry.

The HI-8585 or the HI-8586 along with the HI-8588 or the Hi-8591 line receivers offer the smallest options available to get on and off the ARINC bus.

FEATURES

- Direct ARINC 429 line driver interface in a small package
- On-chip band-gap reference to set output levels
- On-chip line driver slope control and selection by logic input
- Low current 12 to 15 volt supplies
- CMOS / TTL logic pins
- Plastic and ceramic package options surface mount and DIP
- Thermally enhanced SOIC packages
- Industrial & extended temperature ranges

PIN CONFIGURATION

SLP1.5 1	0	8 V+
TX0IN 2		7 TXBOUT
TX1IN 3		6 TXAOUT
GND 4		5 V-
		J

SUPPLY VOLTAGES

V+ = 12V to 15VV- = -12V to -15V

FUNCTION TABLE

TX1IN	TX0IN	SLP1.5	TXAOUT TXBOUT		SLOPE
0	0	X	0V	0V	N/A
0	1	0	-5V	5V	10μs
0	1	1	-5V	5V	1.5μs
1	0	0	5V	-5V	10μs
1	0	1	5V	-5V	1.5μs
1	1	X	0V	0V	N/A

PIN DESCRIPTION TABLE

PIN	SYMBOL	FUNCTION	DESCRIPTION
1	SLP 1.5	LOGIC INPUT	CMOS OR TTL, V+ IS OK
2	TX0IN	LOGIC INPUT	CMOS OR TTL
3	TX1IN	LOGIC INPUT	CMOS OR TTL
4	GND	POWER	GROUND
5	V-	POWER	-12 TO -15 VOLTS
6	TXAOUT	OUTPUT	LINE DRIVER TERMINAL A
7	TXBOUT	OUTPUT	LINE DRIVER TERMINAL B
8	V+	POWER	+12 TO +15 VOLTS

FUNCTIONAL DESCRIPTION

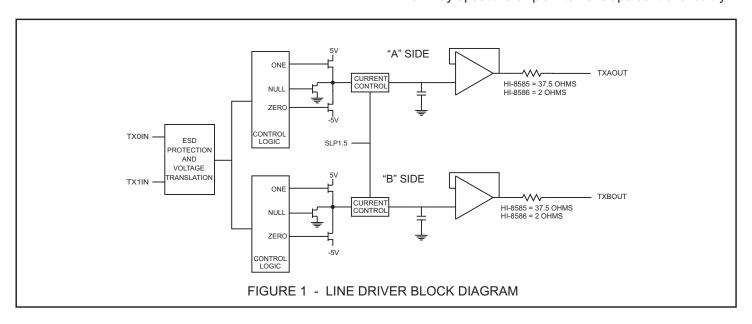
Figure 1 is a block diagram of the line driver. The +5V and -5V levels are generated internally using a on-chip bandgap reference. Currents for slope control are set by zener voltages across on-chip resistors.

The TX0IN and TX1IN inputs receive logic signals from a control transmitter chip such as the HI-6010, HI-3282 or HI-8282. TXAOUT and TXBOUT hold each side of the ARINC bus at Ground until one of the inputs becomes a One. If for example TX1IN goes high, a charging path is enabled to 5V on an "A" side internal capacitor while the "B" side is enabled to -5V. The charging current is selected by the SLP1.5 pin. If the SLP1.5 pin is high, the capacitor is nominally charged from 10% to 90% in 1.5μs. If SLP1.5 is low, the rise and fall times are 10μs.

A unity gain buffer receives the internally generated slopes and differentially drives the ARINC line. Current is limited by the series output resistors at each pin. There are no fuses at the outputs of the HI-8585 as exists on the Hi-8382.

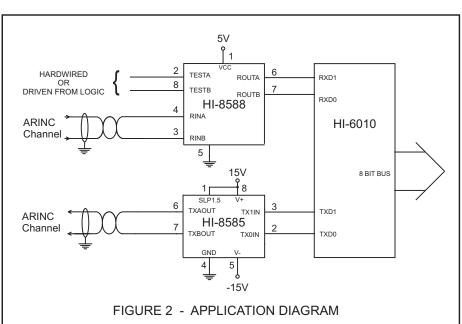
The HI-8585 has 37.5 ohms in series with each output and the HI-8586 has 2 ohms in series with each output. The HI-8586 is for applications where external series resistance is required, typically for lightning protection devices.

Both the HI-8585 and HI-8586 are built using high-speed CMOS technology. Care should be taken to ensure the V+ and V- supplies are locally decoupled and that the input waveforms are free from negative voltage spikes which may upset the chip's internal slope control circuitry.



APPLICATION INFORMATION

Figure 2 shows a possible application of the HI-8585/86 interfacing an ARINC transmit channel from the HI-6010.



ABSOLUTE MAXIMUM RATINGS

Voltages referenced to Ground

Supply voltages 20V V
DC current per input pin+10mA
Power dissipation at 25°C plastic DIP 1.0W, derate 10mW/°C ceramic DIP 0.5W, derate 7mW/°C
Solder Temperature (Reflow) 260°C
Storage Temperature65°C to +150°C

RECOMMENDED OPERATING CONDITIONS

Supply Voltages V++11.4V to +16.5V V11.4V to -16.5V	
Temperature Range Industrial40°C to +85°C Extended55°C to +125°C	

NOTE: Stresses above absolute maximum ratings or outside recommended operating conditions may cause permanent damage to the device. These are stress ratings only. Operation at the limits is not recommended.

DC ELECTRICAL CHARACTERISTICS

V+ = +12V to +15V, V- = -12V to -15V, T_A = Operating Temperature Range (unless otherwise stated)

PARAMETERS	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Input voltage (TX1IN, TX0IN, SLP1.5) high low	VIH VIL		2.1 -		V+ 0.5	volts volts
Input current (TX1IN, TX0IN, SLP1.5) source sink	lih lil	VIN = 0V VIN = 5V	-	-	0.1 0.1	μΑ μΑ
ARINC output voltage (Differential) one zero null	VDIFF1 VDIFF0 VDIFFN	no load; TXAOUT - TXBOUT no load; TXAOUT - TXBOUT no load; TXAOUT - TXBOUT	9.00 -11.00 -0.50	10.00 -10.00 0	11.00 -9.00 0.50	volts volts volts
ARINC output voltage (Ref. to GND) one or zero null	VDOUT VNOUT	no load & magnitude at pin no load	4.50 -0.25	5.00 0	5.50 0.25	volts volts
Operating supply current V+ V-	IDD IEE	SLP1.5 = V+ TX1IN & TX0IN = 0V: no load TX0IN & TX1IN = 0V: no load	- -14.0	6.0 -6.0	14.0 -	mA mA
ARINC output impedence HI-8585 HI-8586	Zout		-	37.5 -	- 2	ohms ohms

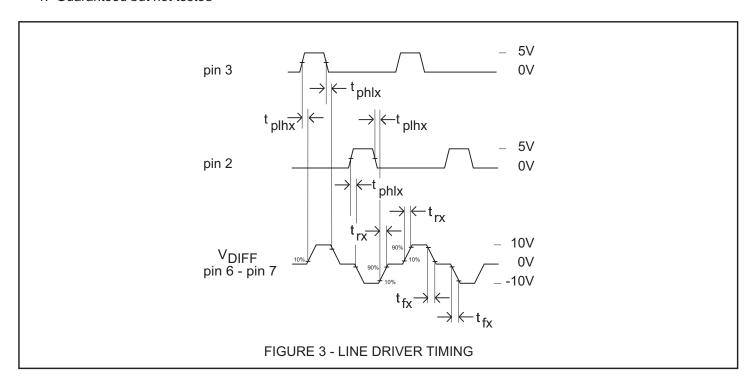
AC ELECTRICAL CHARACTERISTICS

V+ = 15.0V, V- = -15V, T_A = Operating Temperature Range (unless otherwise stated)

PARAMETERS	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Line Driver propagation delay		defined in Figure 3, no load				
Output high to low	t phlx		-	500	-	ns
Output low to high	t plhx		-	500	-	ns
Line Driver transition times						
High Speed		SLP 1.5 = V+				
Output high to low	t fx	pin 1 = logic 1	1.0	1.5	2.0	μs
Output low to high	t _{rx}	pin 1 = logic 1	1.0	1.5	2.0	μs
Low Speed		SLP 1.5 = GND				
Output high to low	t fx	pin 1 = logic 1	5.0	10.0	15.0	μs
Output low to high	t rx	pin 1 = logic 1	5.0	10.0	15.0	μs
Input capacitance (1)						
logic	C _{IN}		-	-	10	pF

Notes:

1. Guaranteed but not tested



PACKAGE THERMAL CHARACTERISTICS

MAXIMUM ARINC LOAD 9, 10

PACKAGE STYLE 1	ARINC 429	SUPPL	Y CURREN	T (mA) ²	JUNCTION TEMP, Tj (°C)			
PACKAGE STILL	DATA RATE	Ta = 25°C	Ta = 85°C	Ta=125°C	Ta = 25°C	Ta = 85°C	Ta=125°C	
8 Lead Plastic DIP	Low Speed ³	16.8	17.2	16.9	58	116	157	
o Lead Flastic Dir	High Speed ⁴	27.3	26.7	25.9	75	132	169	
0.1 1.01 1 5.01.0 5	Low Speed	17.4	17.5	16.9	68	126	166	
8 Lead Plastic ESOIC ⁵	High Speed	27.6	27.1	25.9	97	147	186	
8 Lead Plastic ESOIC ⁶	Low Speed	17.1	17.2	16.7	52	110	151	
o Leau Flasiic ESOIC	High Speed	27.3	27.1	26.2	57	112	157	

TXAOUT and TXBOUT Shorted to Ground 7, 8, 9, 10

PACKAGE STYLE 1	ARINC 429	SUPPL	Y CURREN	T (mA) ²	JUNCTION TEMP, Tj (°C)			
TACKAGE STILL	DATA RATE	Ta = 25°C	Ta = 85°C	Ta=125°C	Ta = 25°C	Ta = 85°C	Ta=125°C	
8 Lead Plastic DIP	Low Speed ³	53.6	50.7	52.2	131	181	217	
o Leau Flasiic DiF	High Speed ⁴	46.9	38.7	42.5	135	181	219	
0.1 LDL (; F0.010.5	Low Speed	46.4	47.6	68.1	167	191	221	
8 Lead Plastic ESOIC ⁵	High Speed	42.1	43.8	67.1	177	212	223	
0.1 1.01 1 50.010 6	Low Speed	48.5	45.6	46.1	112	161	186	
8 Lead Plastic ESOIC ⁶	High Speed	46.8	41.1	40.5	116	168	197	

Notes:

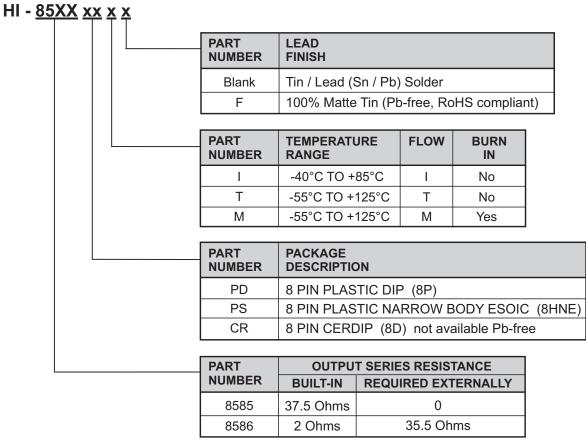
- 1. All data taken in still air on devices soldered to single layer copper PCB (3" X 4.5" X .062").
- 2. At 100% duty cycle, 15V power supplies. For 12V power supplies multiply all tabulated values by 0.8.
- 3. Low Speed: Data Rate = 12.5 Kbps, Load: R = 400 Ohms, C = 30 nF.
- 4. High Speed: Data Rate = 100 Kbps, Load: R = 400 Ohms, C = 10 nF. Data not presented for C = 30 nF as this is considered unrealistic for high speed operation.
- 5. 8 Lead Plastic ESOIC (Thermally enhanced SOIC with built in heat sink). Heat sink not soldered to the PCB.
- 6. 8 Lead Plastic ESOIC (Thermally enhanced SOIC with built in heat sink). Heat sink soldered to the PCB.
- 7. Similar results would be obtained with TXAOUT shorted to TXBOUT.
- 8. For applications requiring survival with continuous short circuit, operation above Tj = 175°C is not recommended.
- 9. Data will vary depending on air flow and the method of heat sinking employed.
- 10. Current values are per supply.

HEAT SINK - ESOIC PACKAGES

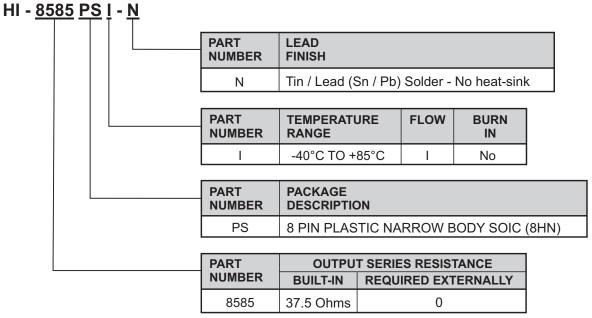
An 8-pin thermally enhanced SOIC package is used for the HI-8585/HI-8586 products. The ESOIC package includes a metal heat sink located on the bottom surface of the device. This heat sink should be soldered down to the printed circuit board for optimum thermal dissipation. The

heat sink is electrically isolated from the chip and can be soldered to any ground or power plane. However, since the chip's substrate is at V+, connecting the heat sink to this power plane is recommended to avoid coupling noise into the circuit.

ORDERING INFORMATION



Legend: ESOIC - Thermally Enhanced Small Outline Package (SOIC) with built-in heat sink



Legend: SOIC - Small Outline Package (No Heat-Sink)

REVISION HISTORY

P/N	Rev	Date	Description of Change
DS8585	М	05/08/08	Clarified temperature ranges and added HI-8585PSI-N to Ordering Information
	N	09/09/11	Replaced references of setting ARINC output levels with zener diodes to using a band-gap reference circuit.
	0	02/08/17	Update package drawings. Update solder reflow temperature.

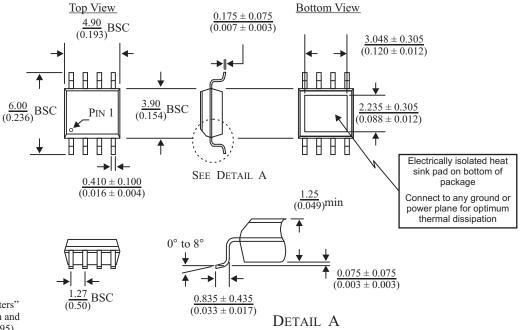
HI-8585 / HI-8586 PACKAGE DIMENSIONS

8-PIN PLASTIC SMALL OUTLINE (ESOIC) - NB

(Narrow Body, Thermally Enhanced)

millimeters (inches)

Package Type: 8HNE

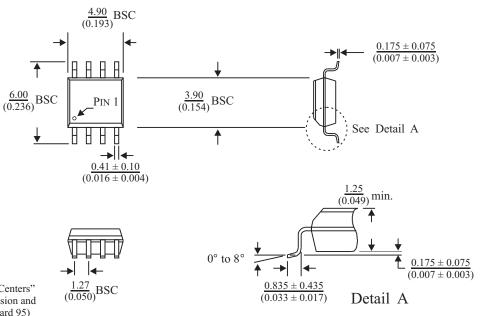


BSC = "Basic Spacing between Centers" is theoretical true position dimension and has no tolerance. (JEDEC Standard 95)

8-PIN PLASTIC SMALL OUTLINE (SOIC) - NB (Narrow Body)

millimeters (inches)

Package Type: 8HN

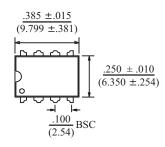


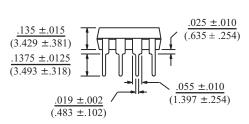
HI-8585 / HI-8586 PACKAGE DIMENSIONS

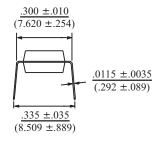
8-PIN PLASTIC DIP

inches (millimeters)

Package Type: 8P





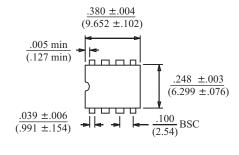


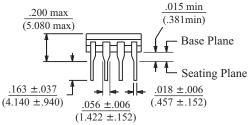
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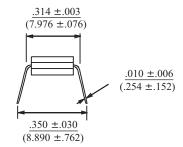
8-PIN CERDIP

inches (millimeters)

Package Type: 8D







BSC = "Basic Spacing between Centers" is theoretical true position dimension and has no tolerance. (JEDEC Standard 95)